

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



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3SK264

N-Channnel Dual Gate MOSFET 15V,30mA,PG=23dB,NF=1.1dB, CP4



Features

- · Enhancement type
- Easy AGC (Cut off at VG2S=0V)
- · Small noise figure
- · Excels in cross modulation characteristics

Specifications

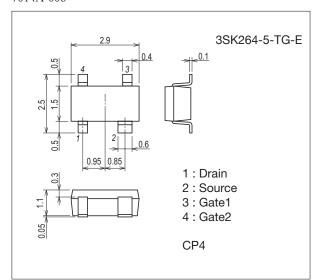
Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Drain-to-Source Voltage	V _{DS}		15	V
Gate1-to-Source Voltage	V _{G1S}		±8	V
Gate2-to-Source Voltage	V _{G2S}		<u>±</u> 8	V
Drain Current	ID		30	mA
Allowable Power Dissipation	PD		200	mW
Channel Temperature	Tch		125	°C
Storage Temperature	Tstg		-55 to +125	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

Package Dimensions

unit : mm (typ) 7014A-006



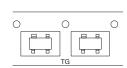
Product & Package Information

• Package : CP4

• JEITA, JEDEC : SC-61, SC-82AB, SOT-143, SOT-343

• Minimum Packing Quantity: 3,000 pcs./reel

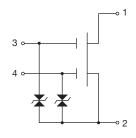
Packing Type: TG



Marking



Electrical Connection



Electrical Characteristics at Ta=25°C

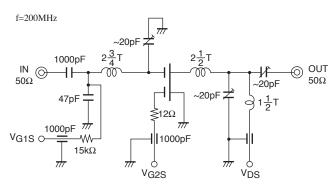
Parameter	Symbol	Conditions	Ratings			Unit
		Conditions	min	typ	max	Offic
Drain-to-Source Voltage	V _{DS}	V _{G1S} =0V, V _{G2S} =0V, I _{DS} =100μA	15			V
Gate1-to-Source Cutoff Voltage	VG1S(off)	V _{DS} =6V, V _{G2S} =4V, I _D =100μA	0	0.7	1.3	V
Gate2-to-Source Cutoff Voltage	V _{G2S} (off)	V _{DS} =6V, V _{G1S} =3V, I _D =100μA	0.1	0.9	1.6	V
Gate1-to-Source Leakage Current	IG1SS	V _{G1S} =±6V, V _{G2S} =V _{DS} =0V			±50	nA
Gate2-to-Source Leakage Current	IG2SS	V _{G2S} =±6V, V _{G1S} =V _{DS} =0V			±50	nA
Zero-Gate Voltage Drain Current	IDSX	VDS=6V, VG1S=1.5V, VG2S=4V	*5		*12	mA
Forward Transfer Admittance	yfs	V _{DS} =6V, I _D =10mA, V _{G2S} =4V, f=1kHz		17		mS
Input Capacitance	Ciss	V50-6V V0 10-0V V000-4V f-1MHz		2.5		pF
Reverse Transfer Capacitance	Crss	VDS=6V, VG1S=0V, VG2S=4V, f=1MHz		0.015	0.03	pF
Power Gain	PG	V _{DS} =6V, I _D =10mA, V _{G2S} =4V, f=200MHz	20	23		dB
Noise Figure	NF	V _{DS} =6V, I _D =10mA, V _{G2S} =4V, f=200MHz		1.1	2.2	dB

 $^{^{\}star}$: The 3SK264 is classified by IDSX as follows : (unit : mA)

Rank	5		
I _{DSX}	5.0 to 12.0		

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

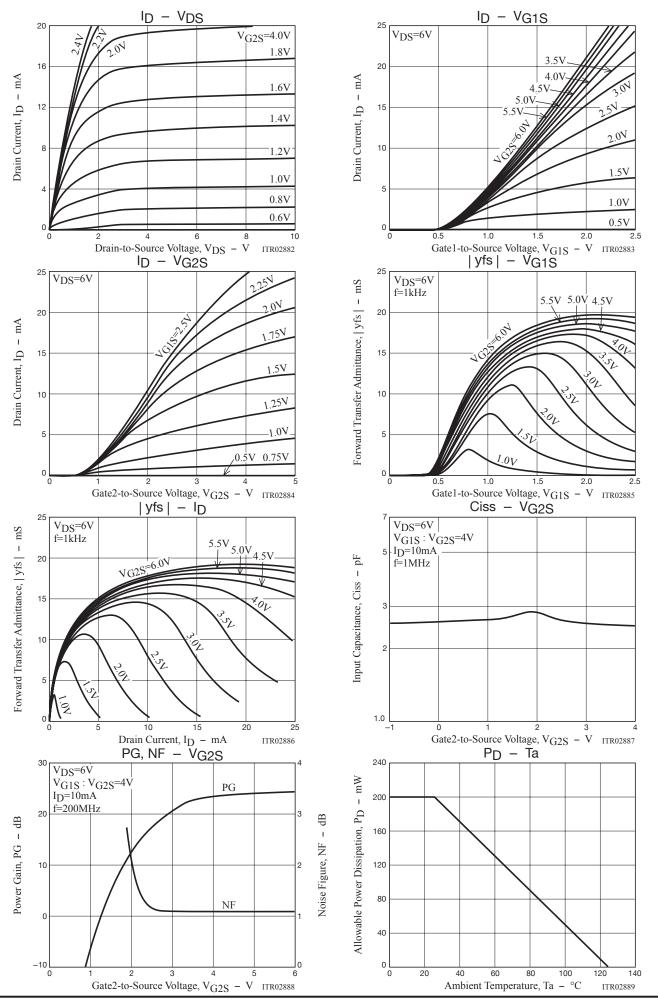
PG, NF Specified Test Circuit



L: 1mmØ enamel wire 10mmØ

Ordering Information

Device	Package	Shipping	memo	
3SK264-5-TG-E	CP4	3,000pcs./reel	Pb-Free	

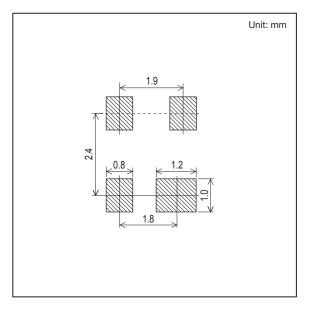


Outline Drawing

3SK264-5-TG-E

Mass (g) Unit 0.013 mm 2. 9±0. 15 0. 4+0.1 0. 5-0. 25 3 5±0.15 2, 5±0.2 0. 6^{+0. 1} 0. 5-0. 15 2 0.95 0.85 0.3±0.1 1. 1±0. 15 O. 1 S *1:Lot indication

Land Pattern Example



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